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Claims

1. A method for coating an implant device, comprising: coating the implant device with a protein;

covalently immobilizing a first substance having an amino group to the protein; and adsorbing a bisphosphonate substance to the first substance, the first substance being different from the bisphosphonate substance.

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- 2. The method according to claim 1 wherein the immobilizing step comprises covalently linking a reactive group such as an amino group of bisphosphonate to the protein.
- 15 3. The method according to claim 1 wherein the adsorbing step comprises using a chemically non-reactive bisphosphonate.
 - 4. The method according to claim 1 wherein the coating steps further comprises using a cross-linked protein.

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- 5. The method according to claim 1 wherein the method further comprises etching a surface of the implant device.
- 6. The method according to claim 1 wherein the method further comprises creating a plurality of protein layers by cross-linking the protein layers with by ethyl-dimethyl-aminopropylcarbodiimide (EDC) and hydroxy-succinimide (NHS).
- 7. The method according to claim 1 wherein the coating step 30 further comprises immobilizing a first protein layer onto a surface of the implant device via an attachment of amino propyl triethoxy silane (APTES).

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8. The method according to claim 7 wherein the coating steps further comprises using glutaraldehyde to chemically bind the APTES and glutaraldehyde to amino groups of the first protein layer.

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- 9. An implant device, comprising:
- a multilayer of protein chemically bound to a surface of the implant device;
- a chemically immobilizable bisphosphonate layer covalently
- 10 bound to the protein film; and
 - a chemically non-reactive bisphosphonate layer non-covalently bound to the first bisphosphonate layer.
- 10. The implant device according to claim 9 wherein the second bisphosphonate layer is bound to the protein film only by non-covalent interactions.